

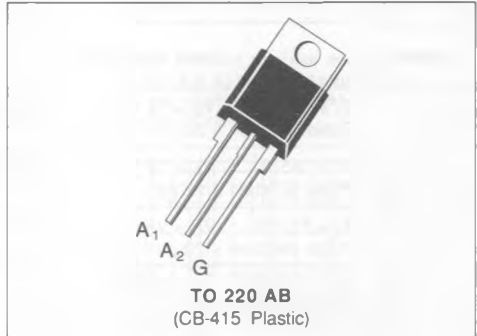


LOGIC LEVEL TRIACS

- $I_{TRMS} = 6 \text{ A}$ at $T_c = 80^\circ\text{C}$.
- $V_{DRM} : 200 \text{ V}$ to 800 V .
- $I_{GT} = 10 \text{ mA}$ (QI-II-III).
- $(di/dt)_c = 3.5 \text{ A/ms}$ @ $(dv/dt)_c = 50 \text{ V}/\mu\text{s}$.
- SUITED FOR LOW POWER TRIGGER CIRCUITS (INTEGRATED CIRCUITS AND MICROPROCESSORS).
- GLASS PASSIVATED CHIP.
- HIGH EFFICIENCY SWITCHING.
- AVAILABLE IN INSULATED VERSION → BTA SERIES (INSULATING VOLTAGE : $2500 V_{RMS}$) OR IN UNINSULATED VERSION → BTB SERIES.
- UL RECOGNIZED FOR BTA SERIES (E81734).

DESCRIPTION

New range suited for applications such as phase control and static switching on inductive or resistive load.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
I_{TRMS}	RMS on-state current (360 ° conduction angle)	$T_c = 80^\circ\text{C}$	6	A
I_{TSM}	Non repetitive surge peak on-state current (T_j initial = 25°C)	$t = 8.3 \text{ ms}$	95	A
		$t = 10 \text{ ms}$	85	
I^2t	I^2t value	$t = 10 \text{ ms}$	36	A^2s
di/dt	Critical rate of rise of on-state current (1)	Repetitive $F = 50 \text{ Hz}$	20	A / μs
		Non Repetitive	100	
T_{sj} T_j	Storage and operating junction temperature range		- 40, + 150 - 40, + 110	$^\circ\text{C}$ $^\circ\text{C}$

Symbol	Parameter	BTA/BTB 06-					Unit
		200 SW	400 SW	600 SW	700 SW	800 SW	
V_{DRM}	Repetitive peak off-state voltage (2)	± 200	± 400	± 600	± 700	± 800	V

(1) Gate supply : $I_G = 100 \text{ mA}$ — $di_G/dt = 1 \text{ A}/\mu\text{s}$.

(2) $T_j = 110^\circ\text{C}$.

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction to ambient	60	°C/W
$R_{th(j-c)} \text{ DC}$	Junction to case for DC	4.8	°C/W
$R_{th(j-c)} \text{ AC}$	Junction to case for 360 ° conduction angle (F = 50 Hz)	3.6	°C/W

GATE CHARACTERISTICS (maximum values)

$P_{GM} = 40 \text{ W}$ ($t = 10 \mu\text{s}$) $P_{G(AV)} = 1 \text{ W}$ $I_{GM} = 4 \text{ A}$ ($t = 10 \mu\text{s}$) $V_{GM} = 16 \text{ V}$ ($t = 10 \mu\text{s}$).

ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions			Quadrants	Min.	Typ.	Max.	Unit
I _{GT}	T _J = 25 °C Pulse duration > 20 μs		V _D = 12 V R _L = 33 Ω	I-II-III			10	mA
V _{GT}	T _J = 25 °C Pulse duration > 20 μs		V _D = 12 V R _L = 33 Ω	I-II-III			1.5	V
V _{GD}	T _J = 110 °C Pulse duration > 20 μs		V _D = V _{DRM} R _L = 3.3 kΩ	I-II-III	0.2			V
I _H *	T _J = 25 °C Gate open	I _T = 100 mA R _L = 140 Ω					25	mA
I _L	T _J = 25 °C Pulse duration > 20 μs V _D = 12 V R _L = 33 Ω I _G = 50 mA			I-III		25		mA
				II		50		
V _{TM} *	T _J = 25 °C I _{TM} = 8.5 A		t _p = 10 ms				1.75	V
I _{DRM} *	T _J = 25 °C	V _{DRM} rated	Gate open				10	μA
	T _J = 110 °C						500	
dv/dt*	T _J = 110 °C Linear slope up to 0.67 V _{DRM} Gate open				50			V/μs
(di/dt) _c *	T _J = 110 °C (dv/dt) _c = 0.1 V/μs				3.5	5		A/ms
	T _J = 110 °C (dv/dt) _c = 50 V/μs				2.7	3.5		
t _{gt}	T _J = 25 °C I _T = 8.5 A		di _G /dt = 1 A/μs V _D = V _{DRM} I _G = 50 mA	I-II-III		2		μs

* For either polarity of electrode A₂ voltage with reference to electrode A₁.

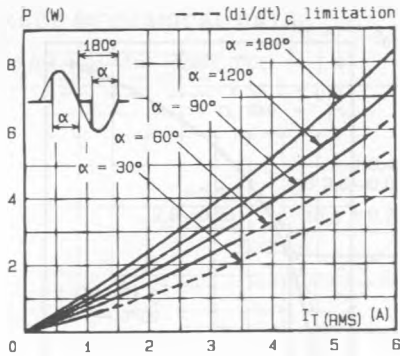


Fig.1 - Maximum mean power dissipation versus RMS on-state current ($f = 60$ Hz).

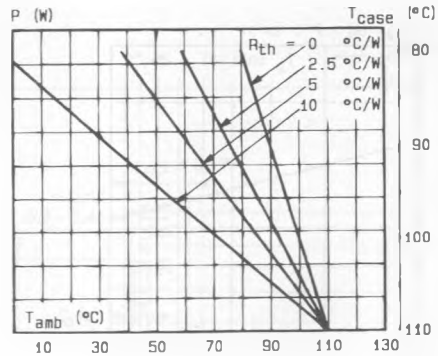


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact.

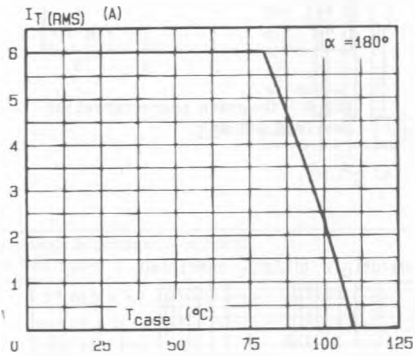


Fig.3 - RMS on-state current versus case temperature.

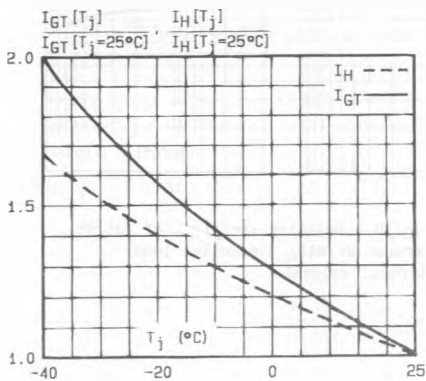


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

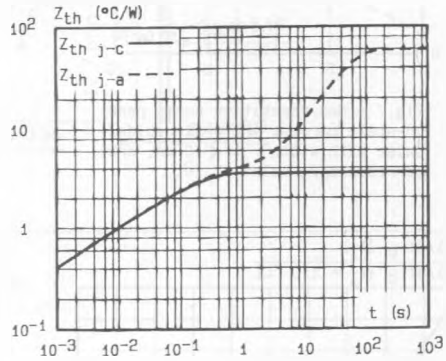


Fig.4 - Thermal transient impedance junction to case and junction to ambient versus pulse duration.

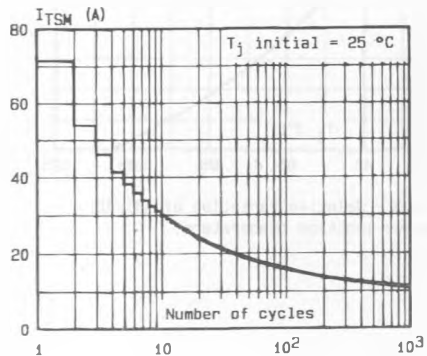


Fig.6 - Non repetitive surge peak on-state current versus number of cycles.

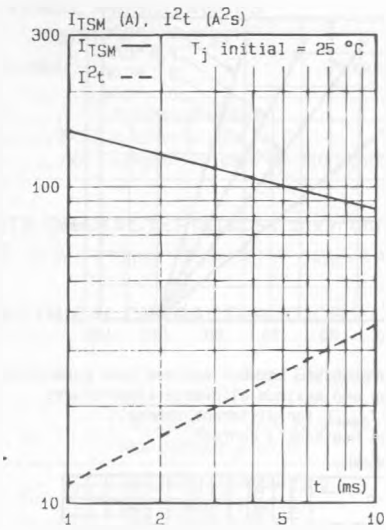


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width : $t \leq 10$ ms, and corresponding value of I^2t .

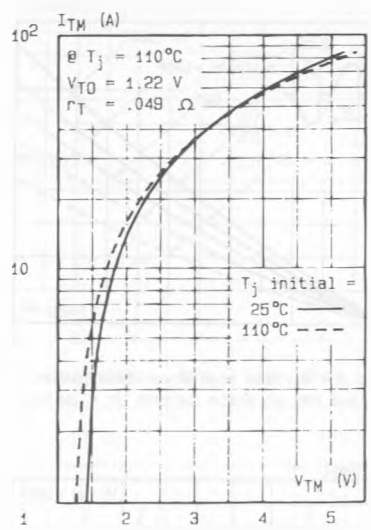


Fig.8 - On-state characteristics (maximum values).

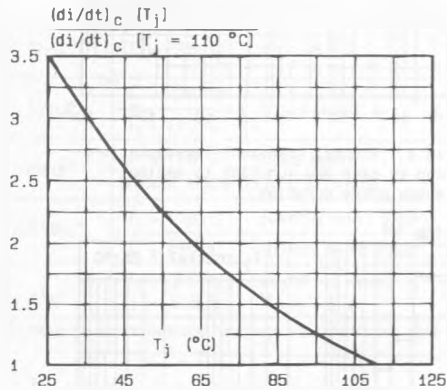


Fig.9 - Relative variation of $(di/dt)_C$ versus junction temperature.

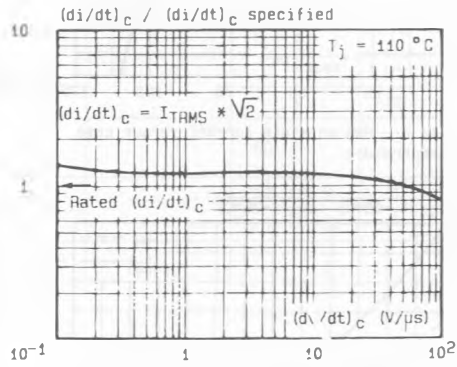


Fig.10 - Relative variation of $(di/dt)_C$ versus $(dv/dt)_C$ (inductive load) (typical values).

